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High-Power NPN Silicon Transistor

... for use as an output device in complementary audio amplifiers to 100-Watts music power per channel.

- High DC Current Gain hFE = 25–100 @ I_C = 7.5 A
- Excellent Safe Operating Area
- Complement to the PNP MJ4502

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30 AMPERE POWER TRANSISTOR NPN SILICON 100 VOLTS 200 WATTS



TO-204AA (TO-3)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCER	100	Vdc
Collector–Base Voltage	V _{CB}	100	Vdc
Collector–Emitter Voltage	VCEO	90	Vdc
Emitter–Base Voltage	V _{EB}	4.0	Vdc
Collector Current	IC	30	Adc
Base Current	IB	7.5	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	200 1.14	Watts W/°C
Operating and Storage Junction Temperature Range	TJ, T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

	Characteristic	Symbol	Max	Unit
Ī	Thermal Resistance, Junction to Case	θ JC	0.875	°C/W

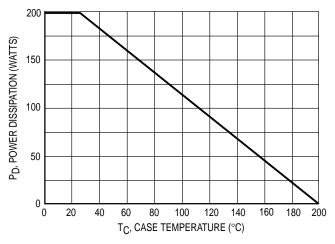


Figure 1. Power-Temperature Derating Curve

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•			
Collector–Emitter Breakdown Voltage ⁽¹⁾ (I _C = 200 mAdc, R _{BE} = 100 Ohms)	BVCER	100	_	Vdc
Collector–Emitter Sustaining Voltage ⁽¹⁾ (I _C = 200 mAdc)	VCEO(sus)	90	_	Vdc
Collector–Base Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0, T_C = 150^{\circ}\text{C})$	ICBO	_ _	1.0 5.0	mAdc
Emitter-Base Cutoff Current (V _{BE} = 4.0 Vdc, I _C = 0)	I _{EBO}	_	1.0	mAdc
ON CHARACTERISTICS ⁽¹⁾				-
DC Current Gain ⁽¹⁾ ($I_C = 7.5 \text{ Adc}$, $V_{CE} = 2.0 \text{ Vdc}$)	hFE	25	100	_
Base–Emitter "On" Voltage (I _C = 7.5 Adc, V _{CE} = 2.0 Vdc)	VBE(on)	_	1.3	Vdc
Collector–Emitter Saturation Voltage (I _C = 7.5 Adc, I _B = 0.75 Adc)	VCE(sat)	_	0.8	Vdc
Base–Emitter Saturation Voltage (I _C = 7.5 Adc, I _B = 0.75 Adc)	V _{BE(sat)}	_	1.3	Vdc
DYNAMIC CHARACTERISTICS				_
Current Gain — Bandwidth Product (I _C = 1.0 Adc, V _{CE} = 10 Vdc, f = 1.0 MHz)	fT	2.0	_	MHz

2.0

 $[\]overline{(1)}$ Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

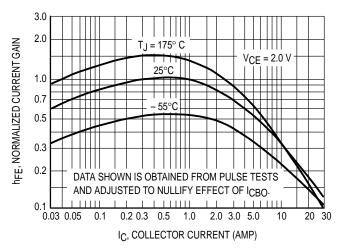


Figure 2. DC Current Gain

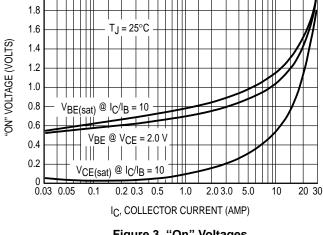


Figure 3. "On" Voltages

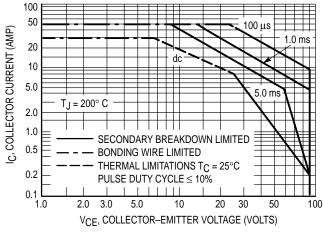
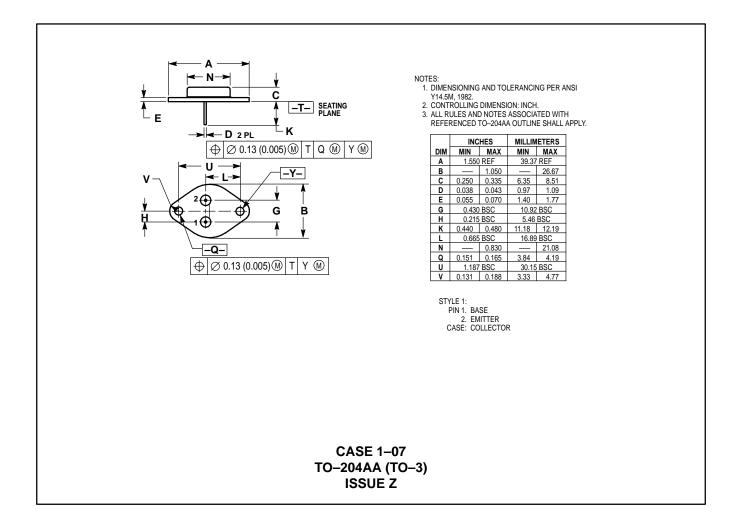


Figure 4. Active Region Safe Operating Area

The Safe Operating Area Curves indicate I_C – V_{CE} limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J, power temperature derating must be observed for both steady state and pulse power conditions.

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PACKAGE DIMENSIONS



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